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[Continued on next page]

(54) Title: NANOPOROUS MATERIALS AND METHODS OF FORMATION THEREOF

(57) Abstract: Low dielectric materials are described herein that comprise a plurality of pores or nanopores in addition to the ultrananopores. It is further contemplated that the low dielectric materials described herein will have a dielectric constant of less than about 3. The dielectric materials are fromed from polymer compositions, wherein the polymer compositions comprise a plurality of monomersand wherein at least one monomer comprises a radical precursor bonded to a structural precursor. Further, methods of forming dielectric materials from polymer compositions are presented. The figure shows the chemical structure for a methyl/t-butyl Low organic Content/Low Organic Siloxane Polymer.

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Documentation searched other than minimum documentation to the	he extent that such documents are included in	the fields searched
Electronic data base consulted during the international search (na Please See Continuation Sheet	me of data base and, where practicable, sear	ch terms used)
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20 November 2002 (20.11.2002)	1 9 050 2002	
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